

74AHC05

HEX INVERTER WITH OPEN DRAIN OUTPUTS

Description

The 74AHC05 provides provides six independent inverters with open drain outputs The device is designed for operation with a power supply range of 2.0V to 5.5V. The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment.

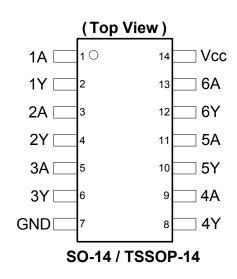
The gates perform the Boolean function:

 $\mathsf{Y}=\overline{\mathsf{A}}$

Features

- Wide Supply Voltage Range from 2.0V to 5.5V
- Outputs Sink 8 mA at V_{CC} = 4.5V
- CMOS Low Power Consumption
- Schmitt Trigger Action at All Inputs
- Inputs can be driven by 3.3 V or 5.5V allowing for voltage translation applications.
- ESD Protection Exceeds JESD 22
 - 200-V Machine Model (A115-A)
 - 2000-V Human Body Model (A114-A)
 - Exceeds 1000-V Charged Device Model (C101C)
- Latch-Up Exceeds 250mA per JESD 78, Class II
- Range of Package Options SO-14 and TSSOP-14
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Pin Assignments



Applications

- General Purpose Logic
- Wide array of products such as:
 - PCs, Networking, Notebooks, Netbooks
 - Computer Peripherals, Hard Drives, CD/DVD ROM
 - TV, DVD, DVR, Set Top Box

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

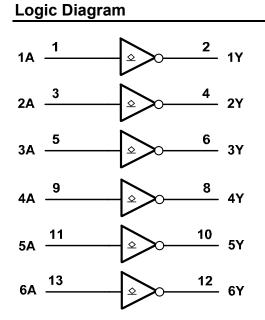
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Pin Descriptions

Pin Number	Pin Name	Function
1	1A	Data Input
2	1Y	Data Output
3	2A	Data Input
4	2Y	Data Output
5	3A	Data Input
6	3Y	Data Output
7	GND	Ground
8	4Y	Data Output
9	4A	Data Input
10	5Y	Data Output
11	5A	Data Input
12	6Y	Data Output
13	6A	Data Input
14	V _{CC}	Supply Voltage



Function Table

Input	Output
Α	Y
L	Z
Н	L

Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	KV
ESD CDM	Charged Device Model ESD Protection	1	KV
ESD MM	Machine Model ESD Protection	200	V
Vcc	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range	-0.5 to +7.0	V
I _{IK}	Input Clamp Current VI < -0.5V	-20	mA
loк	Output Clamp Current V _O < -0.5V	-20	mA
I _{OK} Output Clamp Current V _O > V _{CC} +0.5V		25	mA
I_{O} Continuous Output Current -0.5V < V_{O} V _{CC} +0.5V		+/- 25	mA
Icc	Continuous Current Through V _{CC}	75	mA
I _{GND}	Continuous Current Through GND	-75	mA
T _J Operating Junction Temperature		-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
Ртот	Total Power Dissipation	500	mW

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Recommended Operating Conditions (Note 5) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{CC}	Supply Voltage		2.0	5.5	V
VI	Input Voltage		0	5.5	V
Vo	Output Voltage		0	Vcc	V
Δt/ΔV	Input Transition Rise or Fall Rate	V _{CC} = 3.0V to 3.6V		100	ns/V
ΔυΔν		V _{CC} = 4.5V to 5.5V		20	115/ V
T _A	Operating Free-Air Temperature		-40	+125	°C

Note: 5. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Symbol	Deremeter	Test Conditions	V	T _A = -40°0	C to +85°C	T _A = -40°C	to +125°C	Unit
Symbol	Parameter	lest Conditions	V _{cc}	Min	Мах	Min	Max	Unit
			2.0V	1.5		1.5		
VIH	High-Level Input Voltage		3.0V	2.1		2.1		V
	Voltage		5.5V	3.85		3.85		
			2.0V		0.5		0.5	
VIL	Low-Level Input Voltage		3.0V		0.9		0.9	V
Voltage		5.5V		1.65		1.65		
		I _{OL} = 50μA	2.0V		0.1		0.1	
		I _{OL} = 50μA	3.0V		0.1		0.1	
V _{OL}	Low-Level Output Voltage	I _{OL} = 50μA	4.5V		0.1		0.1	V
	Vollage	I _{OL} = 4mA	3.0V		0.44		0.55	
		I _{OL} = 8mA	4.5V		0.44		0.55	
loz	Z State Leakage Current	$V_{\rm O}$ = 0 to 5.5V	5.5V		±2.5		±10	μA
lı	Input Current	VI = GND to 5.5V	3.6V		±1		±2	μA
Icc	Supply Current	$V_{I} = GND \text{ or } V_{CC}, I_{O} = 0$	3.6V		20		40	μA

Operating Characteristics

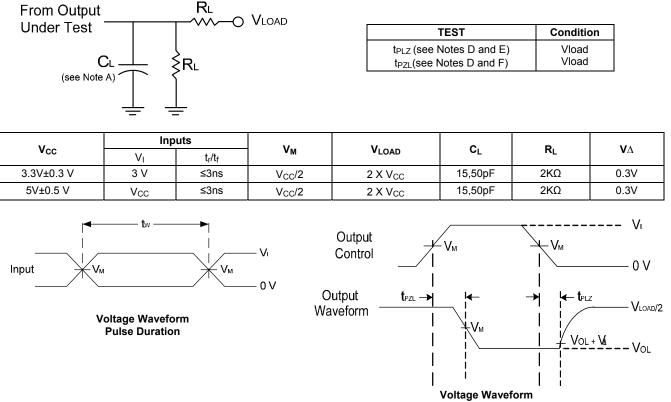
Paramotor		Test Conditions	V _{CC} = 2.0V Typ	V _{CC} = 3.3V Typ	V _{CC} = 5V Typ	Unit
C _{pd}	Power Dissipation Capacitance per Gate	f = 1 MHz	4.3	4.8	5.6	pF
Ci	Input Capacitance	$V_i = V_{CC} - or GND$	4.0	4.0	4.0	pF

Switching Characteristics

Symbol	Symbol Parameter Test		Vcc	T _A = +25°C		-40°C to +85°C		-40°C to +125°C		Unit	
Symbol	Farameter	Conditions	VCC	Min	Тур.	Max	Min	Max	Min	Max	Onit
		Figure 1	3.0V to 3.6V	0.5	4.5	7.9	0.5	9.5	0.5	10.0	
	Propagation	$C_L = 15 pF$	4.5V to 5.5V	0.5	3.2	5.5	0.5	6.5	0.5	7.0	
tPD	Delay A_N to Y_N	Figure 1	3.0V to 3.6V	0.5	6.0	11.4	0.5	13.0	0.5	14.5	ns
		$C_L = 50 pF$	4.5V to 5.5V	0.5	4.5	7.5	0.5	8.5	0.5	9.5	



Parameter Measurement Information



Propagation Delay Times

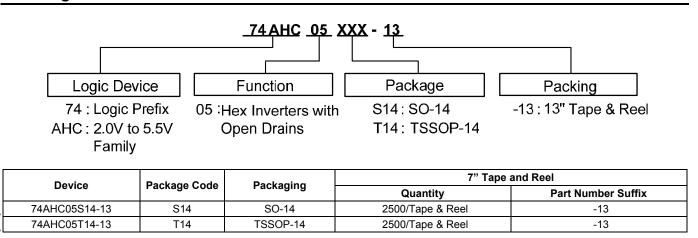
Figure 1. Load Circuit and Voltage Waveforms

Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate \leq 1 MHz.
- C. The inputs are measured one at a time with one transition per measurement.
- D. For the open drain device t_{PLZ} and t_{PZL} are the same as $t_{\mathsf{PD}}.$
- E. t_{PZL} is measured at V_M.
- D. $t_{PLZ}\,$ is measured at V_OL +V_{\Delta}.

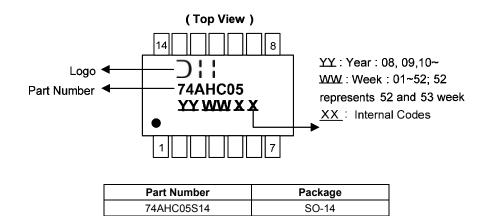


Ordering Information



Marking Information

(1) SO-14, TSSOP-14



TSSOP-14

74AHC05T14

Pb,

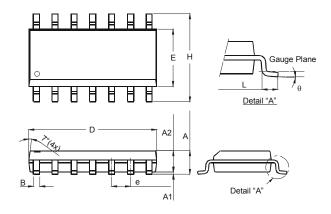
Pb,



Package Outline Dimensions (All dimensions in mm.)

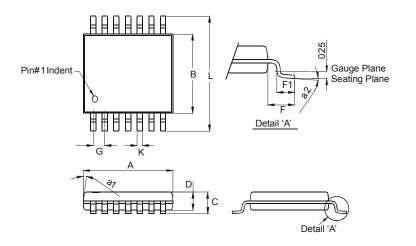
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

Package Type: SO-14



SO-14							
Dim	Min	Max					
Α	1.47	1.73					
A1	0.10	0.25					
A2	1.45	Тур					
В	0.33	0.51					
D	8.53	8.74					
Е	3.80	3.99					
е	1.27	Тур					
н	5.80	6.20					
L	0.38	1.27					
θ	0°	8°					
All Di	mensions	s in mm					

Package Type: TSSOP-14



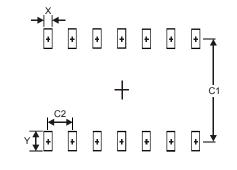
	TSSOP-1	4			
Dim	Min Max				
a1	7° (4X)			
a2	0°	8°			
Α	4.9	5.10			
В	4.30	4.50			
С	_	1.2			
D	0.8	1.05			
F	1.00	Тур			
F1	0.45	0.75			
G	0.65	Тур			
κ	0.19 0.30				
L	6.40 Тур				
All Dir	nensions	s in mm			



Suggested Pad Layout

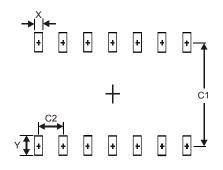
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

Package Type: SO-14



Dimensions	Value (in mm)
Х	0.60
Y	1.50
C1	5.4
C2	1.27

Package Type: TSSOP-14



Dimensions	Value (in mm)
Х	0.45
Y	1.45
C1	5.9
C2	0.65



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